NSN 5962-01-248-9645

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View Online at https://aerobasegroup.com/nsn/5962-01-248-9645

Body Length:		
1.290 inches		
Body Width:		
0.610 inches		
Body Height:		
0.150 inches		
Maximum Power Dissipation Rating:		
1.0 watts		
Operating Tempurature Range:		
-55.0/+125.0 degrees celsius		
Storage Tempurature Range:		
-65.0/+150.0 degrees celsius		
Features Provided:		
Monolithic and bipolar and programmable		
Inclosure Material:		
Ceramic		
Inclosure Configuration:		
Dual-in-line		
Output Logic Form:		
Transistor-transistor logic		
Input Circuit Pattern:		
13 input		
Case Outline Source And Designator:		
D-3 mil-m-38510		
Terminal Surface Treatment:		
Solder		
Voltage Rating And Type Per Characteristic:		
7.0 volts power source		
Memory Device Type:		
Rom		
Memory Capacity:		
Unknown		
Test Data Document:		
49956-954374 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment ma	anufacturer drawing, etc.;	
excludes any specification, standard or other document that may be referenced in a basic governing drawing)		
Terminal Type And Quantity:		
24 printed circuit		
Shelf Life:		
N/a		
Unit Of Measure:		
Demilitarization:		

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